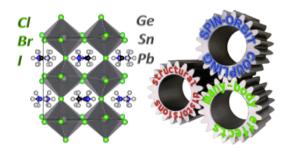
Electronic properties of hybrid organic and inorganic perovskites

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In this poster we, first, present ABINIT based DFT results of the optoelectronic properties of CH₃NH₃PbI₃ and CH₃NH₃BCl₃ (B=Pb, Sn, Ge) hybrid organic-inorganic perovskites (HOP). For CH₃NH₃MCl₃ HOP, the pseudocubic high temperature reference HOP structure (Pm-3m) was used to compare spin-orbit coupling (SOC) induced effect due to the metal atom B.^[1-3] Next, we present 2D layered HOP, which received a renewed interest in recent years due to increased stability under lighting conditions and resistance to humidity and moisture. Their electronic properties show their potential in photovoltaic and optoelectronic applications.^[4]



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